Features

- KPCS Band CDMA and GPS Operation
- Low Current Consumption
- Excellent Noise and IP3 Performance
- Adjustable Third Order Intercept on LNA Stage
- Flexible IF Frequency Range from 80 MHz to 230 MHz
- Excellent Cross Modulation Performance

Applications

- Quad-mode/Dual-band CDMA IS-95/98 Based Mobile Phones with GPS Support
- Other Familiar Applications

Benefits

- High Linearity Eliminates Potential Call Drop Issues Associated with Gain Switching
- Most Compact Integrated Receiver for K-PCS and A-GPS Applications
- IM98 IMD Requirements Met with two Gain States Simplifying Calibration Procedure
- Best in Class A-GPS CascadeGgain for Maximum Take-over
- TX LO Buffer Included
- Few External Components
- Fully ESD Protected

Electrostatic sensitive device. Observe precautions for handling.



Description

The T0352 is a CDMA front-end receiver RFIC designed for dual-band, dual-mode operation. The device supports Korean PCS (K-PCS) CDMA and A-GPS operation. The IF range is from 80 MHz to 230 MHz with external tuning. The K-PCS low noise amplifier has an adjustable third order intercept (IP3) to minimize inter-modulation and cross-modulation effects. The mixers are designed for differential IF outputs (single-ended or differential IF outputs for GPS modes), and they feature excellent linearity and low noise figure.

The T0352 device is available in a 4 mm \times 4 mm MLF package with 24 pins. This front-end receiver is capable of meeting all electrical requirements in accordance with the TIA/EIA 98-C Wireless Communication standard.



2.8 V Dual-band/ Dual-mode RF Receiver for K-PCS/GPS

T0352

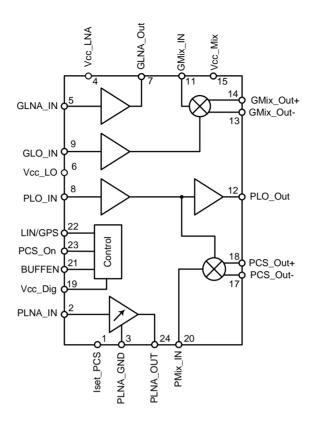
Preliminary (Summary)

Rev. 4579AS-CDMA-11/02



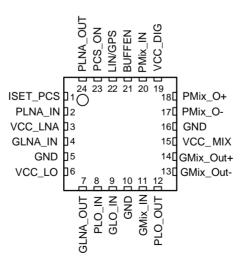


Figure 1. Block Diagram



Pin Configuration

Figure 2. Pinning HP-VFQFP-N24



Pin Description

Pin	Symbol	Function
1	Iset_PCS	Bias resistor for K-PCS LNA. For typical bias use a 560 Ω resistor to ground which set the bias current for HGHL mode.
2	PLNA_IN	PCS LNA input. Requires a DC blocking capacitor and an L-C (shunt C/series L) matching network for optimum gain, intercept and noise performance.
3	Vcc_LNA	Power supply pin for K-PCS LNA. Bypass with a capacitor as close to the pin as possible.
4	GLNA_IN	GPS LNA input. Requires LC match, see Pin 2.
5	GLNA_GND	GPS LNA emitter-ground. The LNA emitter ground should be grounded immediately to the ground plane to reduce stray inductance and capacitance that may affect performance.
6	Vcc_LO	Supply voltage for LO buffer.
7	GLNA_OUT	GPS LNA output.
8	PLO_IN	K-PCS LO input.
9	GLO_IN	GPS LO input.
10	GND	Device ground.
11	GMix_IN	GPS mixer input.
12	PLO_OUT	K-PCS LO buffer output. Internally matched to 100 Ω . Does not require a blocking capacitor.
13	GMix_OUT-	Negative GPS IF output.
14	GMix_OUT+	Positive GPS IF output.
15	Vcc_Mix	Supply voltage for all mixers.
16	GND	Device ground.
17	PMix_OUT-	Negative CDMA IF output.
18	PMix_OUT+	Positive CDMA IF output.
19	Vcc_DIG	Supply voltage for logic control circuits.
20	PMix_IN	K-PCS Mixer RF input.
21	BUFFEN	LO output buffer enable. Set BUFFEN pin HIGH to power up the PCS LO buffer output.
22	LIN/GPS	-
23	PCS_ON	Logic input for activating PCS LNA; Logic high selects PCS. Logic low means inactive.
24	PLNA_OUT	PCS LNA output. Requires a pull-up inductor to Vcc and a series blocking capacitor, which can be used as the output matching network.
_	Paddle	Device ground and heat sink, requires good thermal path; RF reference plane.





Absolute Maximum Ratings

Parameters	Symbol	Value	Unit
Supply voltages, no RF applied	V _{cc}	-0.5 to +4.0	V
Logic control voltages	V _{CTRL}	-0.5 to + V _{CC} +0.5	V
Supply current	I _{CC}	50.0	mA
RF and LO input signals	P _{LO ;} G _{LO;} PLNA_IN; GLNA_IN;	5.0	dBm
I _{SET_PCS} ; I _{SET_CELL}	LNA IP3 Adjustment	1	mA
Operating case temperature	T _c	-40 to +100	°C
Storage temperature	T _{STG}	-55 to +150	°C

Thermal Resistance

Parameters	Symbol	Value	Unit
Junction ambient	R _{thJA}	TBD	K/W

DC Supply Characteristics

Test conditions: Unless otherwise noted, the following conditions apply to typical performance specification under static conditions (no RF applied): $V_{CC} = +2.75$ V, $T_{amb} = 25^{\circ}$ C.

No.	Parameters	Test Conditions	Pin	Symbol	Min.	Тур.	Max.	Unit	Type*
	All Modes								
	Supply voltage		3, 15, 19	V _{CC}	2.7	2.8	3.3	V	
	Control voltage high		23, 21, 22	V _{CTRL}	1.7			V	
	Control voltage low		21, 22, 23	V _{CTRL}			0.5	V	
	LO Rx buffer supply current		15	I _{CC_MIX}		7.0		mA	
	LO Tx buffer current	BUFFEN = High	15	I _{CC_MIX}		6.0		mA	
	Logic-high current		21, 22, 23	I _{CTRL}			100	μA	
	Logic-low current		21, 22, 23	I _{CTRL}	-5.0			μA	
	Power-down supply current	PCS_On, LIN = Low	3, 13, 14, 15, 17, 18, 19, 24	I _{CC}			10	μA	

*) Type means: A = 100% tested, B = 100% correlation tested, C = Characterized on samples, D = Design parameter

AC Electrical Characteristics

No. Parameters Test Conditions Pin Symbol Min. Typ. Max.	Unit	Type*						
conditions: V _{CC} = +2.75 V, T _{amb} = 25°C, all RF inputs and outputs with a return loss of 10 dB minimum.								
Test conditions: Unless otherwise noted, the following conditions apply to typical performance specification under static								

No.	Parameters	Test Conditions	Pin	Symbol	Min.	Тур.	Max.	Unit	Type*	
	General Performance	General Performance								
	Operating frequency	K-PCS band	2, 20	f _{PCS}	1840	1855	1870	MHz		
	range	A-GPS band	4, 11	f _{GPS}		1575.42		MHz		
	LO frequency range	K-PCS band:	8	f _{LOPCS}	1656		1686	MHz		
		IF = 183.6 MHz	8	f _{LOPCS}	2023		2053	MHz		
		GPS band:	9	f _{LOGPS}		1391.82		MHz		
		IF = 183.6 MHz	9	f _{LOGPS}		1759.02		MHz		
	IF frequency range	K-PCS and GPS Band	13, 14, 17, 18	f _{IF}	80	85	230	MHz		
	LO input power level	K-PCS and GPS Band	8, 9	P _{LO}	-10	-5	0	dBm		
	LO Tx buffer output power level	K-PCS band; not matched at dedicated frequency	12	P _{LOOUT}	-8	-3		dBm		

*) Type means: A = 100% tested, B = 100% correlation tested, C = Characterized on samples, D = Design parameter

Cascade RF Electrical Characteristics (K-PCS Band)

Test conditions: Unless otherwise noted, the following conditions apply to typical performance specification under static conditions: $V_{CC} = +2.75 \text{ V}$, $T_{amb} = 25^{\circ}\text{C}$, RF = 1960 MHz; LO = 2045 MHz; IF = 85 MHz; LO input = -5.0 dBm; RF input = -30 dBm (high gain mode)

No.	Parameters	Test Conditions	Pin	Symbol	Min.	Тур.	Max.	Unit	Type*
	Combined LNA an	d Mixer Performance (CDM	IA Modul	ation)					
	High-gain High-lin	earity Mode (HGHL)							
	Gain			G		26		dB	
	Noise figure	PCS_On = High;		NF		2.2		dB	
	Input IP3	LIN = High		IIP3		-1.5		dBm	
	Supply current			I _{CC}		30		mA	
	High-gain Low-line	earity Mode (HGLL, Paging	Mode)						
	Gain			G		25.3		dB	
	Noise figure	PCS_On = High;		NF		2.2		dB	
	Input IP3	LIN = Low		IIP3		-5.3		dBm	
	Supply current			I _{CC}		24		mA	

*) Type means: A = 100% tested, B = 100% correlation tested, C = Characterized on samples, D = Design parameter





Cascade RF Electrical Characteristics (GPS Band)

Test conditions: Unless otherwise noted, the following conditions apply to typical performance specification under static conditions: $V_{CC} = +2.75$ V, $T_{amb} = 25^{\circ}$ C, RF = 1575.42 MHz; LO = 1490.42 MHz; IF = 85 MHz; LO input = -5.0 dBm; RF input = -45 dBm

No.	Parameters	Test Conditions	Pin	Symbol	Min.	Тур.	Max.	Unit	Type*
	Combined LNA an	Combined LNA and Mixer Performance							
	A-GPS LNA PERF	A-GPS LNA PERFORMANCE							
	Gain			G		37		dB	
	Noise figure	PCS_On = Low;		NF		1.5		dB	
	Input IP3	LIN = High		IIP3		-17.5		dBm	
	Supply current			I _{CC}		21		mA	

*) Type means: A = 100% tested, B = 100% correlation tested, C = Characterized on samples, D = Design parameter

Typical Electrical Characteristics LNA and Mixer Separately (K-PCS Band)

Test conditions: Unless otherwise noted, the following conditions apply to typical performance specification under static conditions: $V_{CC} = +2.75 \text{ V}$, $T_{amb} = 25^{\circ}\text{C}$, RF = 1960 MHz; LO = 2045 MHz; IF = 85 MHz; LO input = -5.0 dBm; RF input = -25 dBm (high gain mode)

No.	Parameters	Test Conditions	Gain (dB)	NF (dB)	IIP3 (dBm)	Type*			
	K-PCS Band, High-gain High-linearity Mode (HGHL); CDMA Modulation								
	K-PCS LNA	DCC On Llink LIN Llink	15.5	1.6	9.0				
	K-PCS mixer	PCS_On = High; LIN = High	13.5	6.2	11.0				
	K-PCS Band, High-gain Low-linearity Mode (HGLL); CDMA Modulation								
	K-PCS LNA	DCS On - High: LIN - Low	15	1.6	7.5				
	K-PCS mixer	PCS_On = High; LIN = Low	13.3	6.0	7.5				

*) Type means: A = 100% tested, B = 100% correlation tested, C = Characterized on samples, D = Design parameter

Typical Electrical Characteristics LNA and Mixer separately (GPS Band)

Test conditions: Unless otherwise noted, the following conditions apply to typical performance specification under static conditions: V_{CC} = +2.75 V, T_{amb} = 25°C, RF = 1575.42 MHz; LO = 1490.42 MHz; IF = 85 MHz; LO input = -5.0 dBm; RF input = -35 dBm

No.	Parameters	Test Conditions	Gain (dB)	NF (dB)	IIP3 (dBm)	Type*
	A-GPS Mode					
	GPS LNA	PCS On - High: LIN - Low	19.5	1.5	-2.8	
	GPS Mixer	PCS_On = High; LIN = Low	17.5	5.9	-3.0	

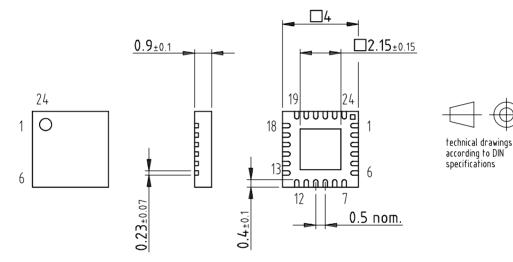
*) Type means: A = 100% tested, B = 100% correlation tested, C = Characterized on samples, D = Design parameter

Ordering Information

Extended Type Number	Package	Remarks
T0352	HP-VFQFP-N24	4 mm × 4 mm

Package Information

Package: HP-VFQFP-N24 (acc. JEDEC OUTLINE No. MO-220) Dimensions in mm



Drawing-No.: 6.543-5086.01-4 Issue: 1; 26.02.02

Note: 1. GND solder mask opening is not centered on the package.





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